Diode Semiconductor Device - Page 1 of 1



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Inc	losure Material:
	ass and metal
	erall Length:
	00 inches
	rminal Length:
	50 inches
Ov	erall Diameter:
0.4	50 inches
Мс	unting Method:
Те	rminal
Fe	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	con
Vo	Itage Rating In Volts Per Characteristic:
20	0.0 reverse voltage, peak
Cu	rrent Rating Per Characteristic:
60	00 amperes forward current, average absolute
Ма	ximum Operating Tempurature Per Measurement Point:
17	0.0 degrees celsius case
Те	rminal Type And Quantity:
2 f	errule
Sp	ecification Data:
80	131-release1811 professional/industrial association specification
Sh	elf Life:
N/a	à
Un	it Of Measure:
De	militarization:
No	
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